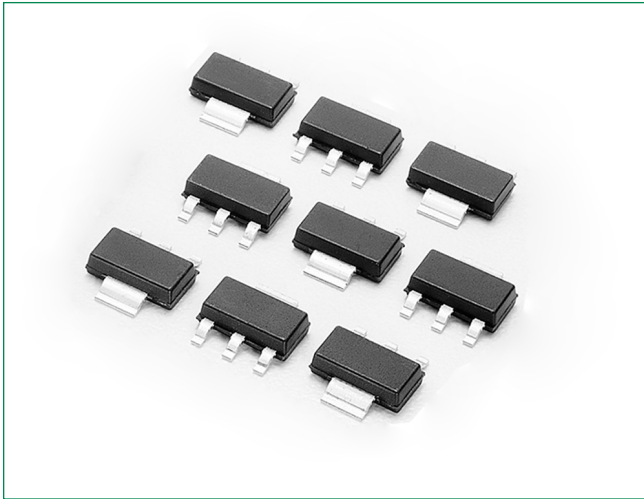




MAC08BT1, MAC08MT1



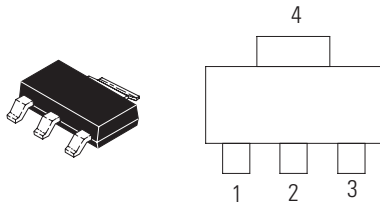
Description

Designed for high volume, low cost, industrial and consumer applications such as motor control; process control; temperature, light and speed control.

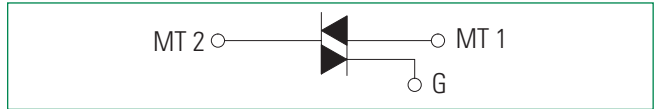
Features

- Sensitive Gate Trigger Current in Four Trigger Modes
- Blocking Voltage to 600 Volts
- Glass Passivated Surface for Reliability and Uniformity
- Surface Mount Package
- Pb-Free Packages are Available

Pin Out



Functional Diagram



Additional Information



Resources



Accessories

Maximum Ratings ($T_J = 25^\circ\text{C}$ unless otherwise noted)

| Rating | Symbol | Value | Unit |
|---|--|-------------|--------------------|
| Peak Repetitive Off-State Voltage (Note 1) (Gate Open, Sine Wave 50 to 60 Hz, $T_J = -40^\circ$ to 110°C) | V_{DRM}^* V_{RRM} | 200 600 | V |
| On-State RMS Current (Full Cycle Sine Wave, 60 Hz, $T_C = 80^\circ\text{C}$) | $I_{\text{T (RMS)}}$ | 0.8 | A |
| Peak Non-Repetitive Surge Current (One Full Cycle Sine Wave, 60 Hz, $T_C = 25^\circ\text{C}$) | I_{TSM} | 8.0 | A |
| Circuit Fusing Consideration ($t = 8.3$ msec) | I^2t | 0.4 | A ² sec |
| Peak Gate Power (Pulse Width ≤ 10 μsec , $T_C = 80^\circ\text{C}$) | P_{GM} | 5.0 | W |
| Average Gate Power ($t = 8.3$ msec, $T_C = 80^\circ\text{C}$) | $P_{\text{G(AV)}}$ | 0.1 | W |
| Operating Junction Temperature Range | T_J | -40 to +110 | $^\circ\text{C}$ |
| Storage Temperature Range | T_{stg} | -40 to +150 | $^\circ\text{C}$ |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

- V_{DRM} and V_{RRM} for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; however, positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

Thermal Characteristics

| Rating | Symbol | Value | Unit |
|--|-----------------------|-------|--------------------|
| Thermal Resistance, Junction-to-Ambient PCB Mounted per Figure 1 | $R_{\theta\text{JA}}$ | 156 | $^\circ\text{C/W}$ |

- These ratings are applicable when surface mounted on the minimum pad sizes recommended.
- 1/8" from case for 10 seconds.

Electrical Characteristics - OFF ($T_C = 25^\circ\text{C}$ unless otherwise noted)

| Characteristic | Symbol | Min | Typ | Max | Unit |
|---|--|-----|-----|-----|---------------|
| †Peak Repetitive Blocking Current ($V_{\text{AK}} = V_{\text{DRM}} = V_{\text{RRM}}$; Gate Open) | I_{DRM}^* I_{RRM} | - | - | 10 | μA |
| | | - | - | 200 | mA |

Electrical Characteristics - ON ($T_C = 25^\circ\text{C}$ unless otherwise noted; Electricals apply in both directions)

| Characteristic | Symbol | Min | Typ | Max | Unit |
|--|-----------------|-----|-----|-----|------|
| Peak On-State Voltage (Note 2) ($I_{\text{TM}} = \pm 1.1$ A) | V_{TM} | - | - | 1.9 | V |
| Gate Trigger Current (Continuous dc) ($V_D = 12$ V, $R_L = 100$ Ω) | I_{GT} | - | - | 10 | mA |
| Holding Current ($V_D = 12$ V, Gate Open, Initiating Current = ± 20 mA) | I_{H} | - | - | 5.0 | mA |
| Gate Trigger Voltage (Continuous dc) ($V_D = 12$ V, $R_L = 100$ Ω) | V_{GT} | - | - | 2.0 | V |

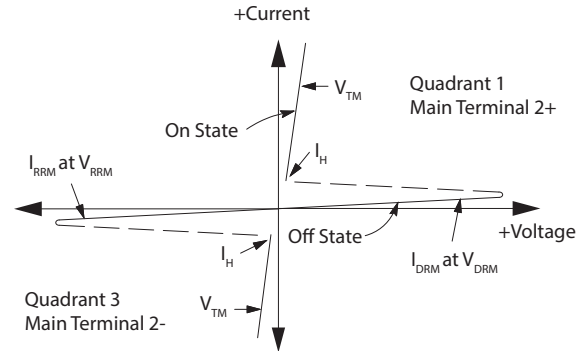
- Pulse Test: Pulse Width ≤ 2.0 ms, Duty Cycle $\leq 2\%$.

Dynamic Characteristics

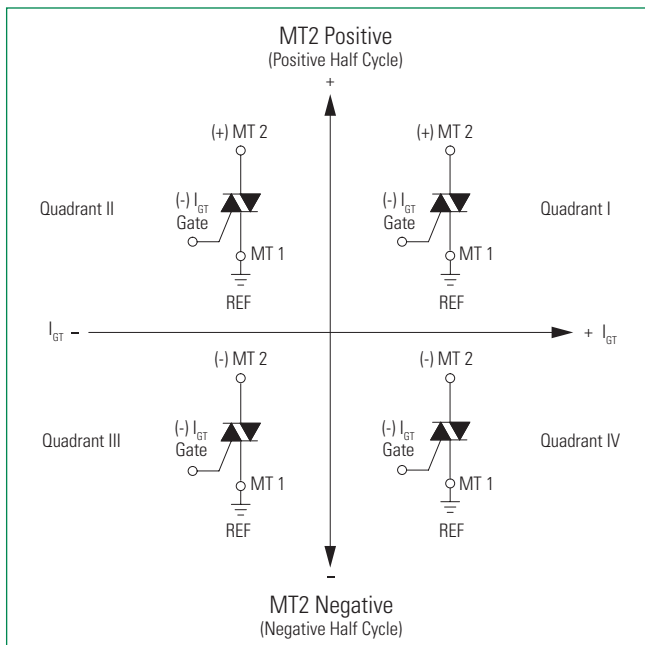
| Characteristic | Symbol | Min | Typ | Max | Unit |
|---|--------------|-----|-----|-----|------------------|
| Critical Rate of Rise of Commutation Voltage ($f = 250$ Hz, $I_{\text{TM}} = 1.0$ A, Commutating $di/dt = 1.5$ A/mS On-State Current Duration = 2.0 mS, $V_{\text{DRM}} = 200$ V, Gate Unenergized, $T_C = 110^\circ\text{C}$, Gate Source Resistance = 150 Ω , See Figure 10) | (di/dt)c | 1.5 | - | - | A/ms |
| Critical Rate of Rise of Off-State Voltage ($V_D = 0.67 \times V_{\text{DRM}}$, Exponential Waveform, Gate Open, $T_J = 110^\circ\text{C}$) | dV/dt | 10 | - | - | V/ μs |

Voltage Current Characteristic of SCR

| Symbol | Parameter |
|-----------|---|
| V_{DRM} | Peak Repetitive Forward Off State Voltage |
| I_{DRM} | Peak Forward Blocking Current |
| V_{RRM} | Peak Repetitive Reverse Off State Voltage |
| I_{RRM} | Peak Reverse Blocking Current |
| V_{TM} | Maximum On State Voltage |
| I_H | Holding Current |

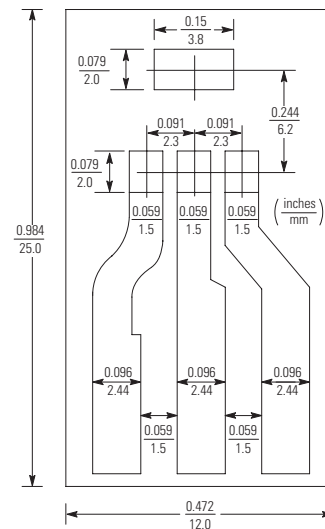


Quadrant Definitions for a Triac



All Polarities are referenced to MT1.
With in-phase signals (using standard AC lines) quadrants I and III are used

Figure 1. PCB for Thermal Impedance and Power Testing of SOT-223



**BOARD MOUNTED VERTICALLY IN CINCH 8840 EDGE CONNECTOR.
BOARD THICKNESS = 65 MIL., FOIL THICKNESS = 2.5 MIL.
MATERIAL: G10 FIBERGLASS BASE EPOXY**

Figure 2. On-State Characteristics

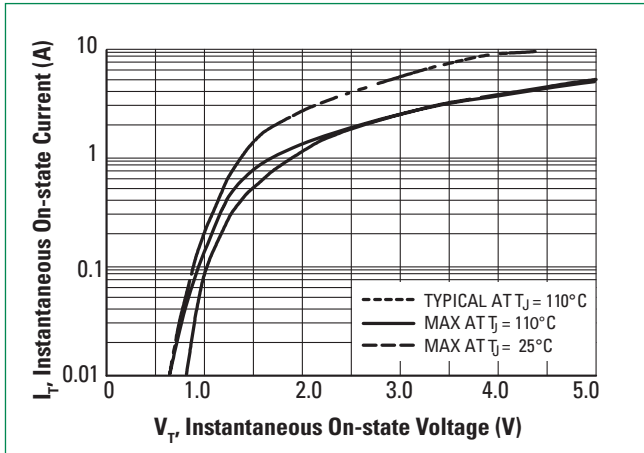


Figure 3. Junction to Ambient Thermal Resistance vs. Copper Tab Area

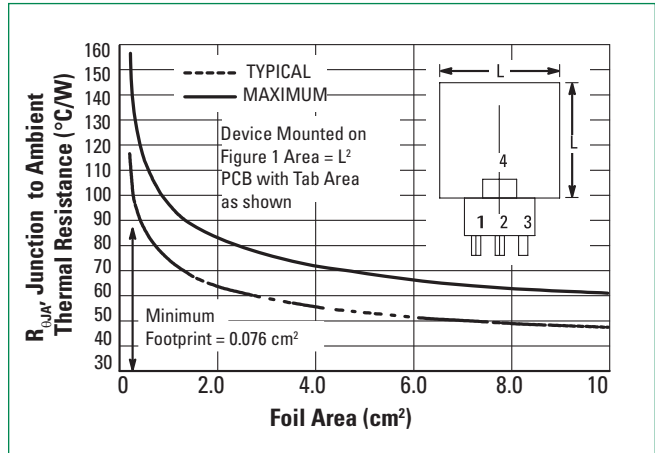


Figure 4. Current Derating, Minimum Pad Size Reference: Ambient Temperature

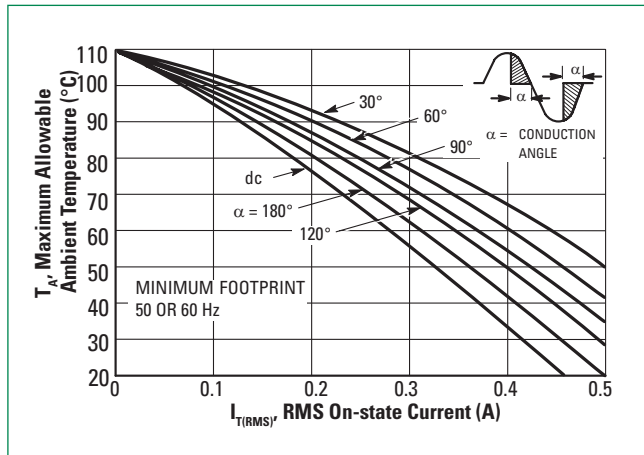


Figure 5. Current Derating, 1.0 cm Square Pad Reference: Ambient Temperature

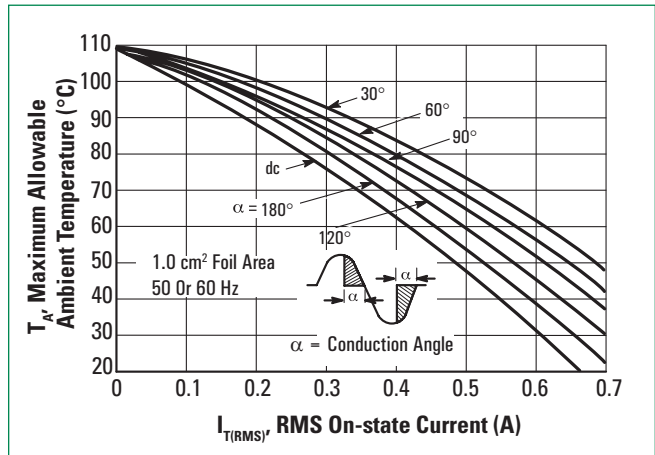


Figure 6. Current Derating, 2.0 cm Square Pad Reference: Ambient Temperature

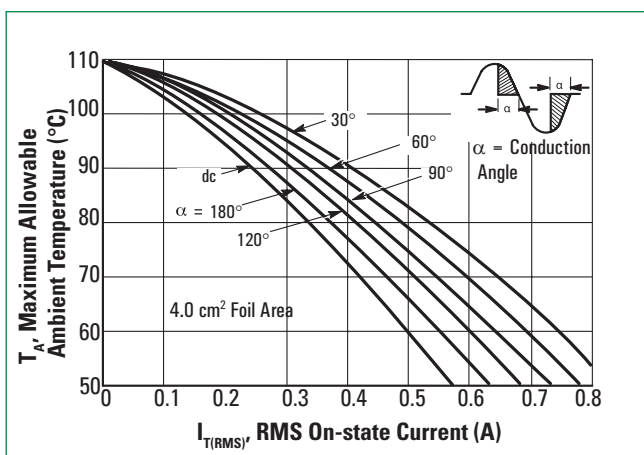


Figure 7. Current Derating Reference: MT2 Tab

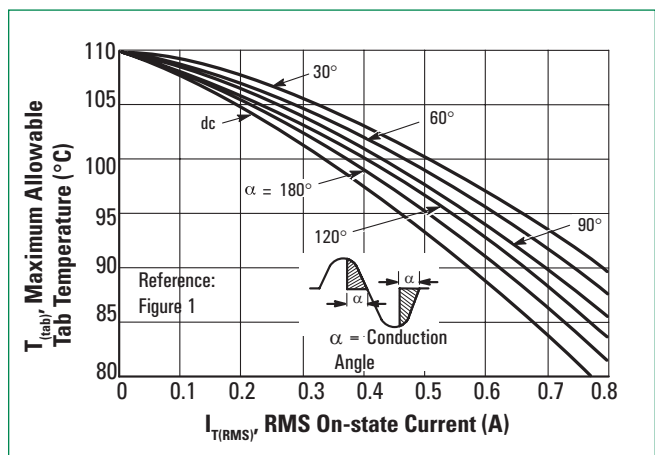


Figure 8. Power Dissipation

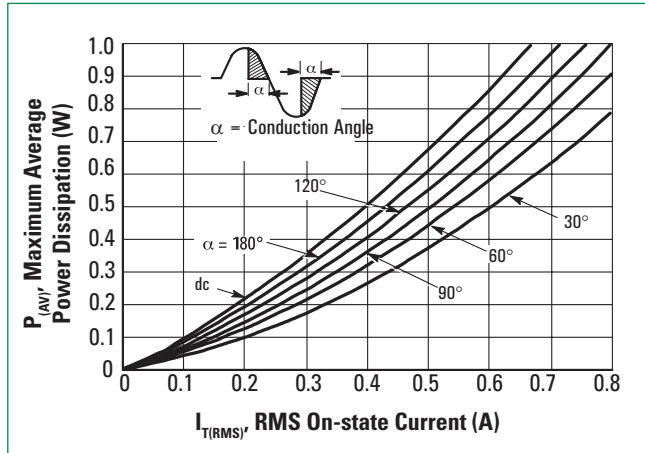


Figure 9. Thermal Response, Device Mounted on Figure 1 Printed Circuit Board

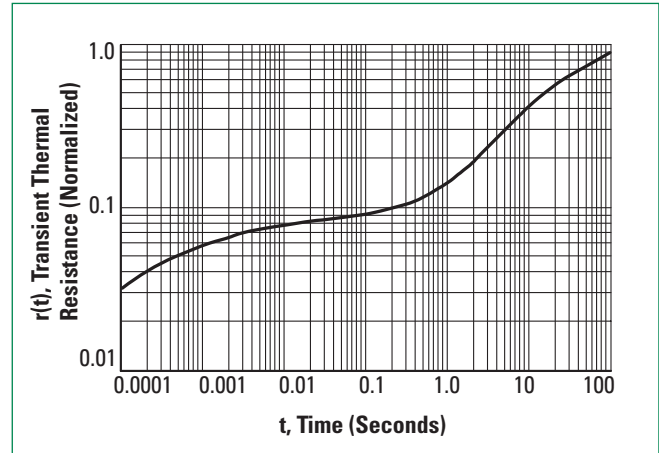


Figure 10. Simplified Test Circuit to Measure the Critical Rate of Rise of Commutating Current (di/dt)

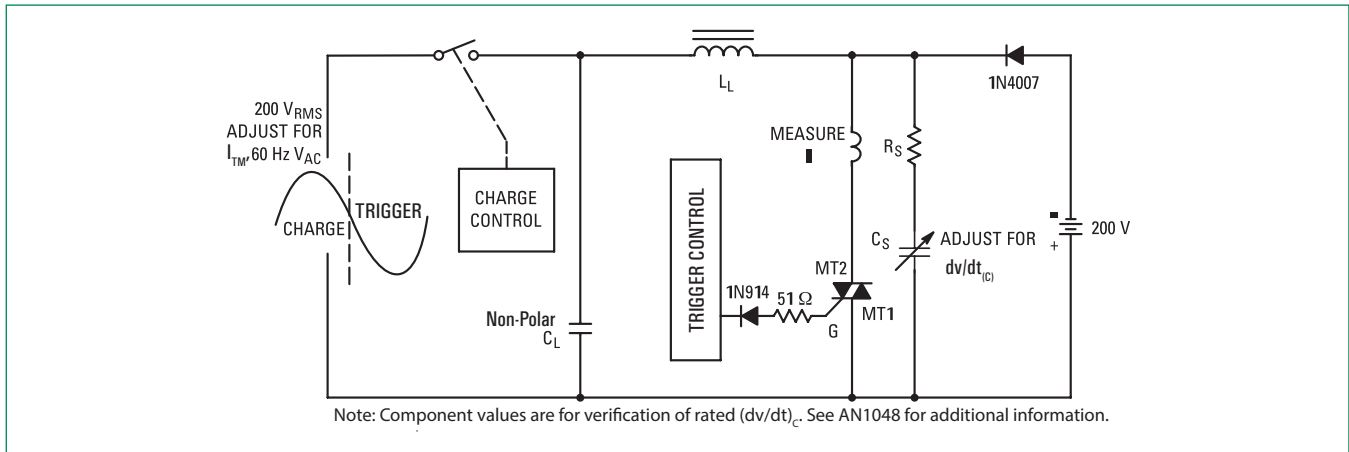


Figure 11. Typical Commutating dv/dt versus Current Crossing Rate and Junction Temperature

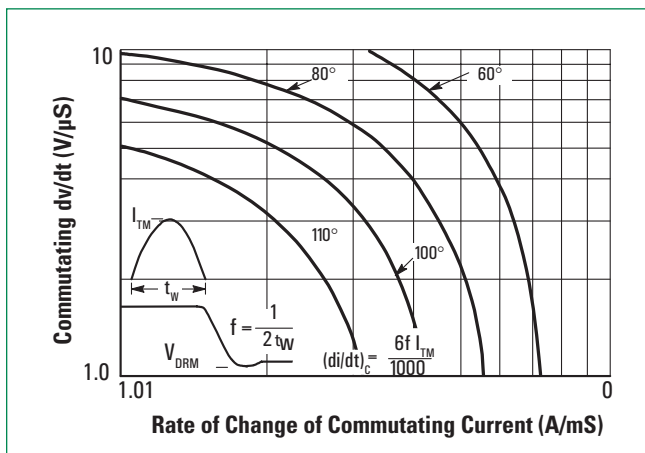


Figure 12. Typical Commutating dv/dt versus Junction Temperature at 0.8 Amps RMS

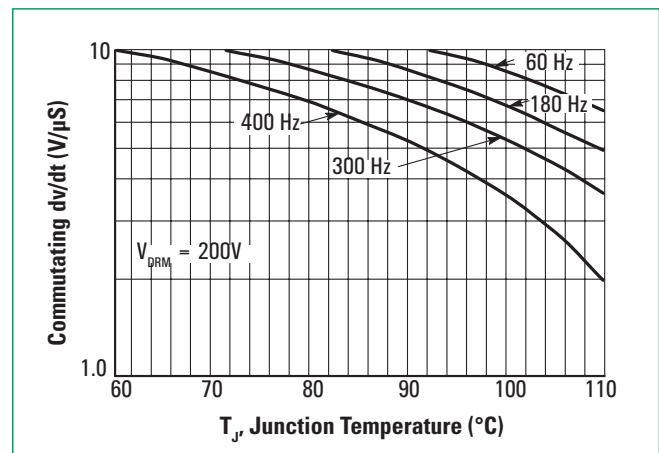


Figure 13. Exponential Static dv/dt versus Gate – Main Terminal 1 Resistance

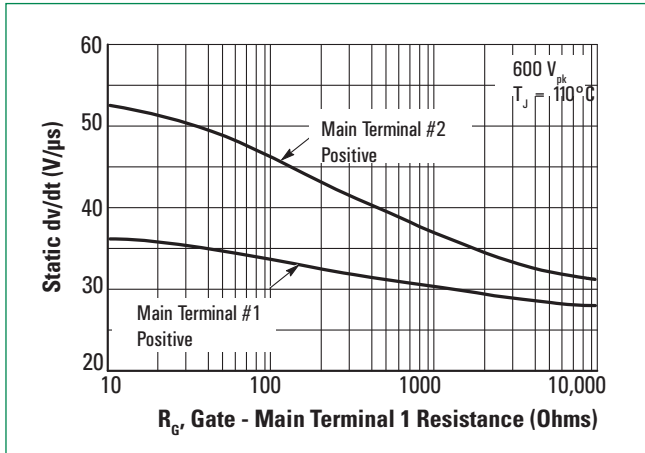


Figure 14. Typical Gate Trigger Current Variation

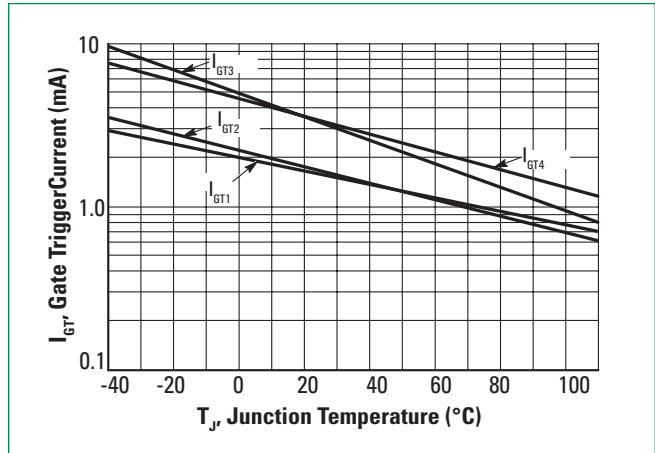


Figure 15. Typical Holding Current Variation

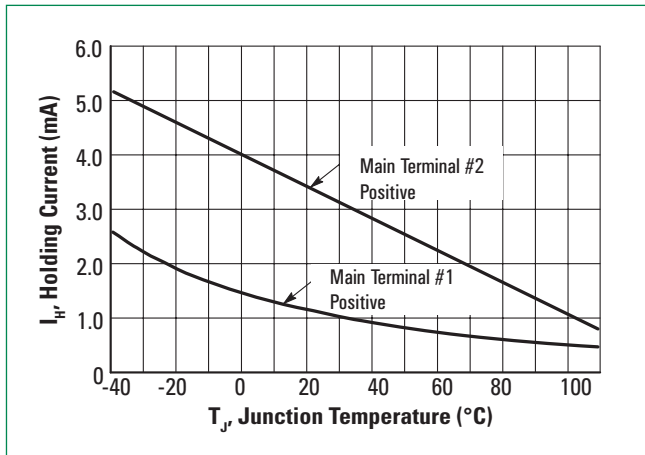
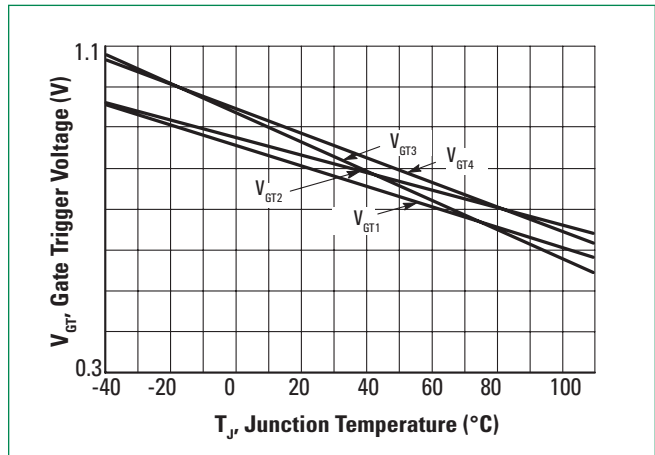
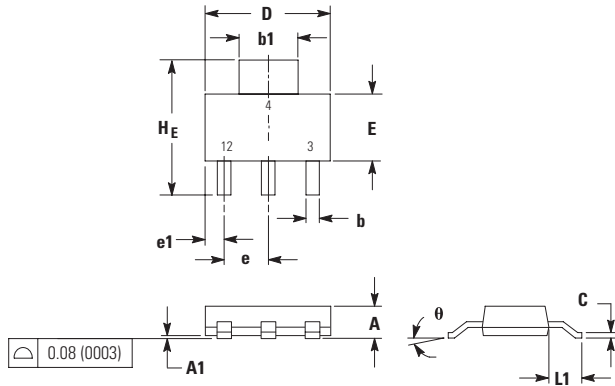


Figure 16. Gate Trigger Voltage Variation



Dimensions



| Dim | Inches | | | Millimeters | | |
|-----|--------|-------|-------|-------------|------|------|
| | Min | Nom | Max | Min | Nom | Max |
| A | --- | --- | 0.071 | --- | --- | 1.80 |
| A1 | 0.001 | 0.003 | 0.005 | 0.02 | 0.07 | 0.13 |
| b | 0.026 | 0.030 | 0.033 | 0.66 | 0.75 | 0.84 |
| b1 | 0.114 | 0.118 | 0.122 | 2.90 | 3.00 | 3.10 |
| c | 0.009 | 0.011 | 0.014 | 0.23 | 0.29 | 0.35 |
| D | 0.260 | 0.260 | 0.264 | 6.60 | 6.60 | 6.71 |
| E | 0.130 | 0.138 | 0.146 | 3.30 | 3.50 | 3.70 |
| e | --- | 0.091 | --- | --- | 2.30 | --- |
| e1 | 0.030 | 0.037 | 0.045 | 0.75 | 0.95 | 1.15 |
| L1 | 0.059 | 0.069 | 0.079 | 1.50 | 1.75 | 2.00 |
| HE | 0.264 | 0.276 | 0.287 | 6.7 | 7.00 | 7.3 |
| θ | 0° | --- | 10° | 0° | --- | 10° |

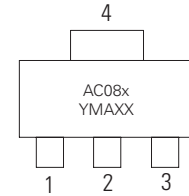
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

| Pin Assignment | |
|----------------|-----------------|
| 1 | Main Terminal 1 |
| 2 | Main Terminal 2 |
| 3 | Gate |
| 4 | Main Terminal 2 |

Part Marking System

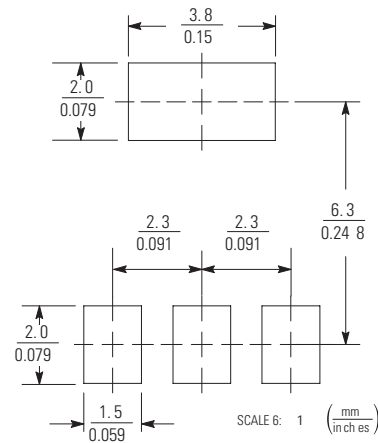


**SOT-223
Case 318E
Style 11**



AC08X = Device Code
x = D, M, or N
Y = Year
M = Month
A = Assembly Site
XX = Lot Serial Code
G = Pb-Free Package

Soldering Footprint



Ordering Information

| Device | Package Type | Shipping |
|-----------|-------------------|--------------------|
| MAC08BT1 | SOT-223 | 1000 / Tape & Reel |
| MAC08BT1G | SOT-223 (Pb-Free) | 1000 / Tape & Reel |
| MAC08MT1 | SOT-223 | 1000 / Tape & Reel |
| MAC08MT1G | SOT-223 (Pb-Free) | 1000 / Tape & Reel |

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